

FODM3011, FODM3012, FODM3022, FODM3023, FODM3052, FODM3053 4-Pin Full Pitch Mini-Flat Package Random-Phase Triac Driver Output Optocouplers

Features

- Compact 4-pin surface mount package (2.4 mm maximum standoff height)
- Peak blocking voltage 250V (FODM301X) 400V (FODM302X) 600V (FODM305X)
- Available in tape and reel quantities of 2500.
- Add "NF098" for new construction version with 260°C max. reflow temperature rating
- UL, C-UL and VDE certifications pending

Applications

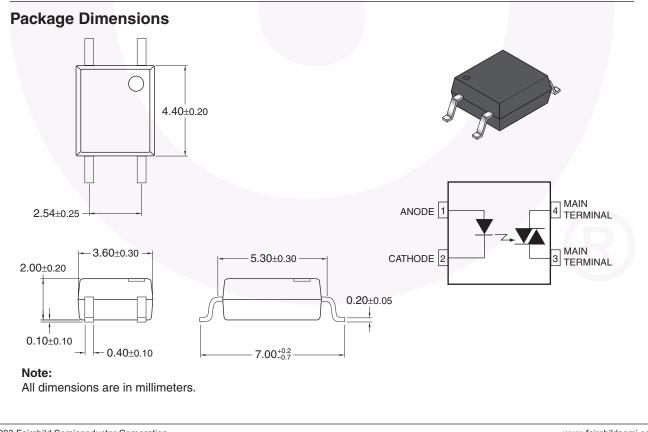
- Industrial controls
- Traffic lights
- Vending machines

Applications (Continued)

- Solid state relay
- Lamp ballasts
- Solenoid/valve controls
- Static AC power switch
- Incandescent lamp dimmers
- Motor control

Description

The FODM301X, FODM302X, and FODM305X series consists of a GaAs infrared emitting diode driving a silicon bilateral switch housed in a compact 4-pin mini-flat package. The lead pitch is 2.54mm. They are designed for interfacing between electronic controls and power triacs to control resistive and inductive loads for 115V/240V operations.



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Absolute Maximum Ratings ($T_A = 25^{\circ}C$ unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Value	Units
TOTAL PACKA	GE				1
T _{STG}	Storage Temperature			-55 to +150	°C
T _{OPR}	Operating Temperature			-40 to +100	°C
EMITTER	·				
I _{F (avg)}	Continuous Forward Current			60	mA
I _{F (pk)}	Peak Forward Current (1µs pulse, 300	Peak Forward Current (1µs pulse, 300pps.)			А
V _R	Reverse Input Voltage			3	V
PD	Power Dissipation (No derating required over operating temp. range)			100	mW
DETECTOR					
I _{T(RMS)}	On-State RMS Current			70	mA (RMS)
V _{DRM}	Off-State Output Terminal Voltage	oltage FODM3011/FODM3012		250	V
		FODM	3022/FODM3023	400	
		FODM	3052/FODM3053	600	
P _D	Power Dissipation (No derating require	ting required over operating temp. range)			mW

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Electrical Characteristics ($T_A = 25^{\circ}C$)

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Typ.*	Max.	Unit
EMITTER							
V _F	Input Forward Voltage	I _F = 10mA	All		1.20	1.5	V
I _R	Reverse Leakage Current	$V_{R} = 3V, T_{A} = 25^{\circ}C$	All		0.01	100	μA
DETECTO	R				•		
I _{DRM}	Peak Blocking Current Either Direction	Rated V _{DRM} , $I_F = 0^{(1)}$	All		2	100	nA
dV/dt	Critical Rate of Rise of Off-State Voltage	I _F = 0 (Figure 8) ⁽²⁾	FODM3011, FODM3012, FODM3022, FODM3023		10		V/µs
			FODM3052, FODM3053	1,000			

Transfer Characteristics

Symbol	DC Characteristics	Test Conditions	Device	Min.	Тур.*	Max.	Unit
I _{FT}	LED Trigger Current	Main Terminal Voltage = 3V ⁽³⁾	FODM3011, FODM3022, FODM3052			10	mA
			FODM3012, FODM3023, FODM3053			5	
Ι _Η	Holding Current, Either Direction		All		300		μA
V _{TM}	Peak On-State Voltage Either Direction	I _{TM} = 100mA peak	All		1.7	3	V

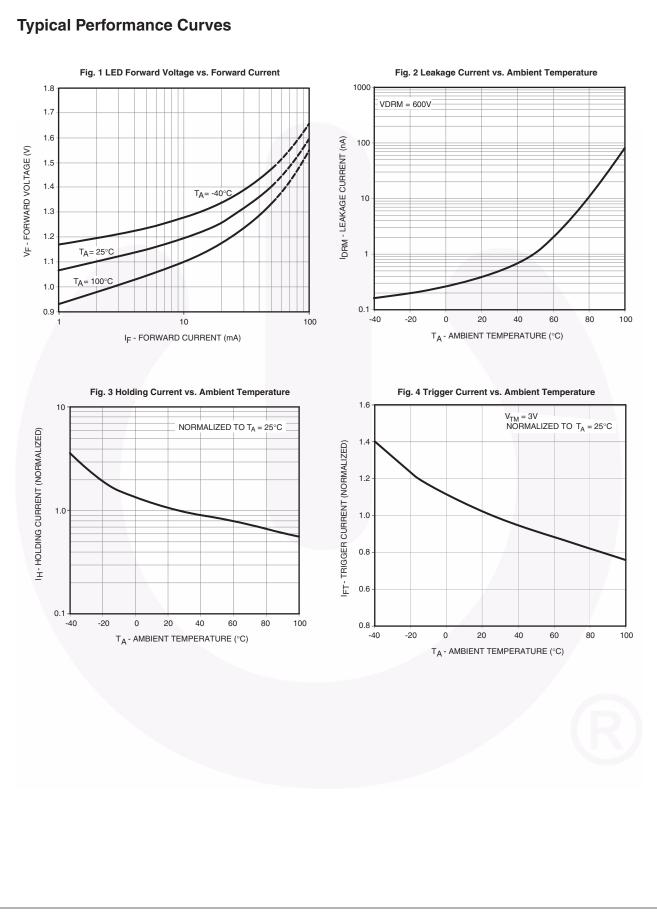
Isolation Characteristics

Symbol	Characteristic	Test Conditions	Device	Min.	Тур.*	Max.	Unit
V _{ISO}	Steady State Isolation Voltage	1 Minute, R.H. = 40% to 60%	All	3750			VRMS

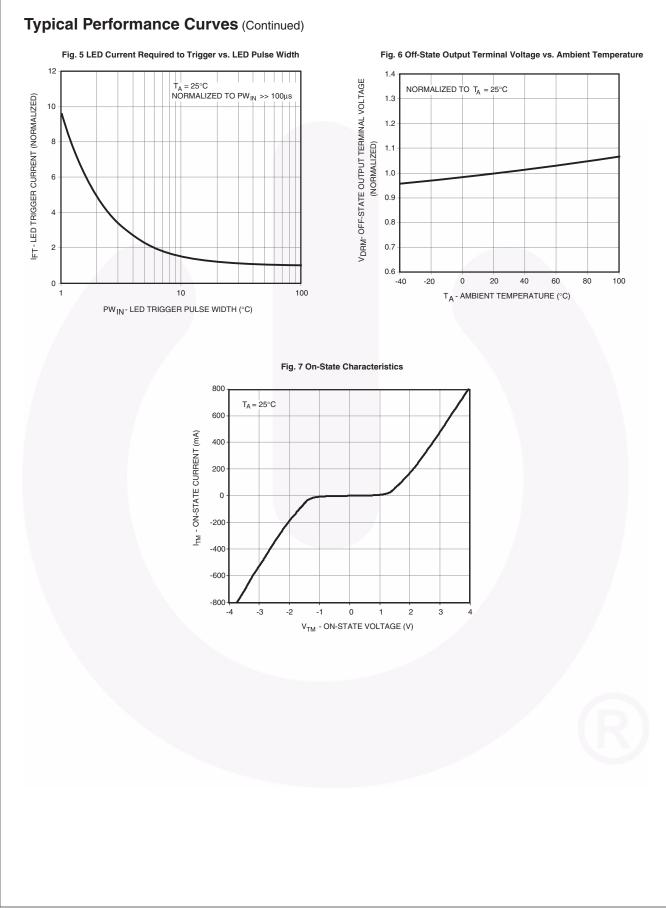
*All typicals at $T_A = 25^{\circ}C$

Notes:

- 1. Test voltage must be applied within dv/dt rating.
- 2. This is static dv/dt. See Figure 1 for test circuit Commutating dv/dt is function of the load-driving thyristor(s) only.
- 3. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (10mA for FODM3011, FODM3022, and FODM3052, 5mA for FODM3012, FODM3023, and FODM3053) and absolute max I_F (60mA).

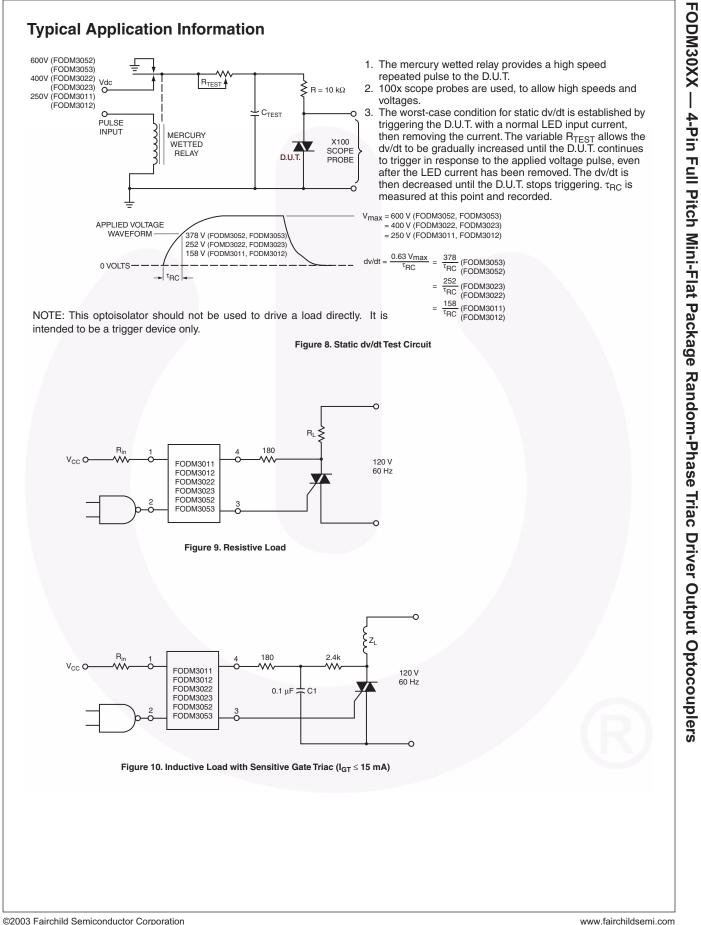


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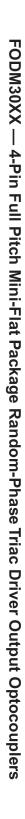


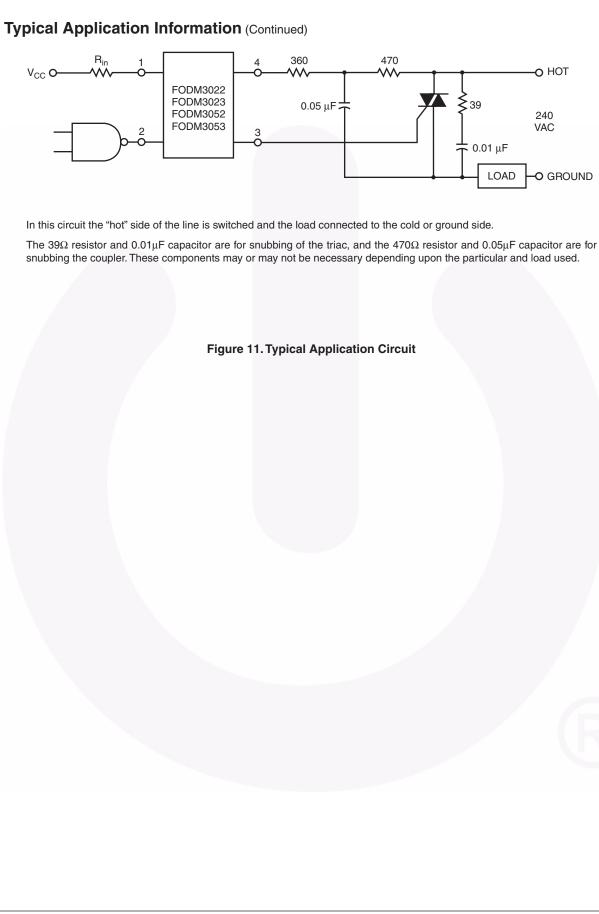
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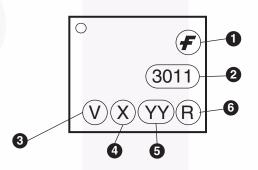
Ordering Information

Option	Description
V_NF098	VDE Approved
R2_NF098	Tape and Reel (2500 units)
R2V_NF098	Tape and Reel (2500 units) and VDE Approved

Note:

To specify the new construction version with 260°C max reflow peak temperature rating: Add "NF098" to the end of the part number. The non NF098 version is rated for 230°C peak reflow temperature.

Marking Information



Definiti	ons				
1	Fairchild logo				
2	Device number				
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)				
4	One digit year code				
5	Two digit work week ranging from '01' to '53'				
6	Assembly package code				

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Tape Specific	ations			
				P_2 D_0 E D_0 P_2 D_0 D_1
				2.54 Pitch
	Description		Symbol	Dimensions
	Tape Width		W	12.00±0.4
	Tape Thickness		t	0.35±0.02
	Sprocket Hole Pitch		Po	4.00±0.20
	Sprocket Hole Dia.		D ₀	1.55±0.20
	Sprocket Hole Location		E	1.75±0.20
	Pocket Location		F	5.50±0.20
			P ₂	2.00±0.20
	Pocket Pitch		Р	8.00±0.20
	Pocket Dimension		A ₀	4.75±0.20
			B ₀	7.30±0.20
			K ₀	2.30±0.20
	Pocket Hole Dia.		D ₁	1.55±0.20
	Cover Tape Width		W ₁	9.20
	Cover Tape Thickness		d	0.065±0.02
	Max. Component Rotation or Til	t		20° max

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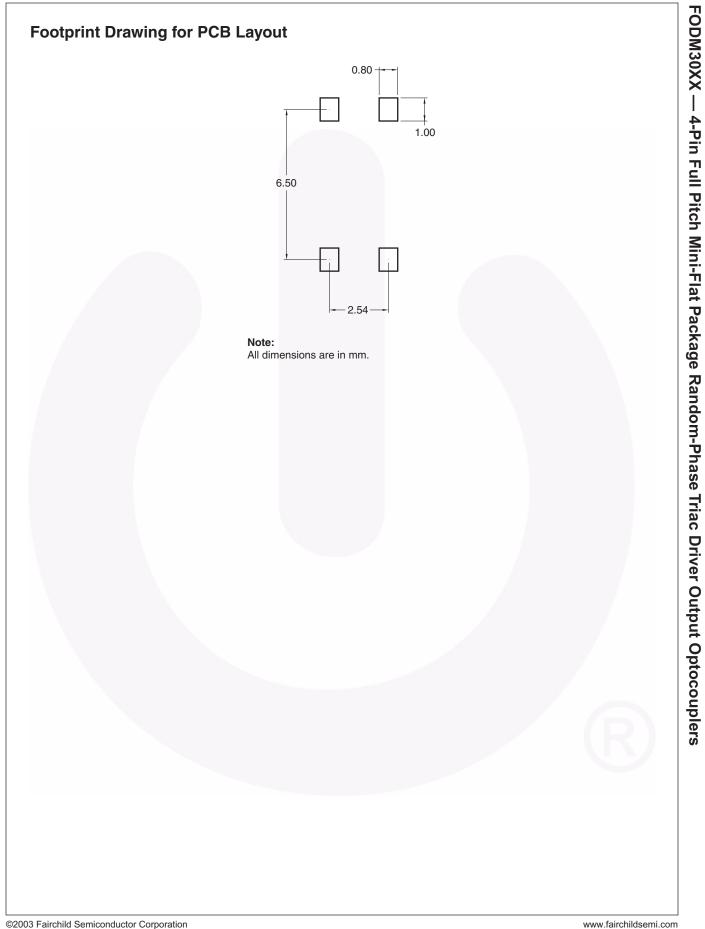
Devices Per Reel

Reel Diameter

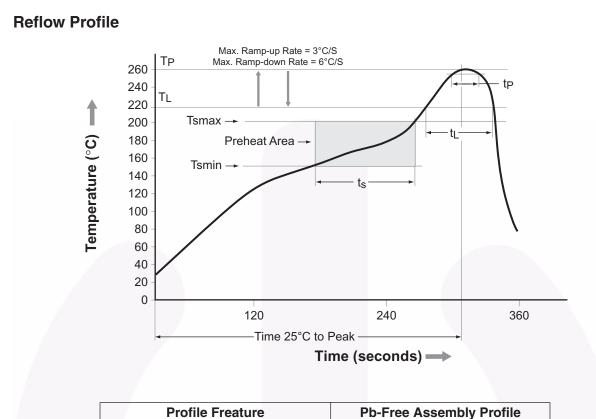
2500

330 mm (13")

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Profile Freature	Pb-Free Assembly Profile		
perature Min. (Tsmin)	150°C		
perature Max. (Tsmax)	200°C		
(t _S) from (Tsmin to Tsmax)	60–120 seconds		
p-up Rate (t _L to t _P)	3°C/second max.		
dous Temperature (T _L)	217°C		
(t _L) Maintained Above (T _L)	60–150 seconds		
Body Package Temperature	260°C +0°C / –5°C		
(t _P) within 5°C of 260°C	30 seconds		
p-down Rate (T _P to T _L)	6°C/second max.		
25°C to Peak Temperature	8 minutes max.		
dous Temperature (T_L) (t_L) Maintained Above (T_L) T_L T_L T_L T_L T_L T_L	217°C 60–150 seconds 260°C +0°C / –5°C 30 seconds 6°C/second max.		

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